

# MOS FIELD EFFECT POWER TRANSISTOR 2SJ302, 302-Z

# SWITCHING P-CHANNEL POWER MOS FET INDUSTRIAL USE

#### **DESCRIPTION**

The 2SJ302 is P-channel MOS Field Effect Transistor designed for solenoid, motor and lamp driver.

#### **FEATURES**

Low On-state Resistance

RDS(on) 
$$\leq 0.1 \Omega$$
 (Vgs = -10 V, lp = -8 A)  
RDS(on)  $\leq 0.24 \Omega$  (Vgs = -4 V, lp = -6 A)

- Low Ciss Ciss = 1 200 pF TYP.
- Built-in G-S Gate Protection Diode

#### QUALITY GRADE

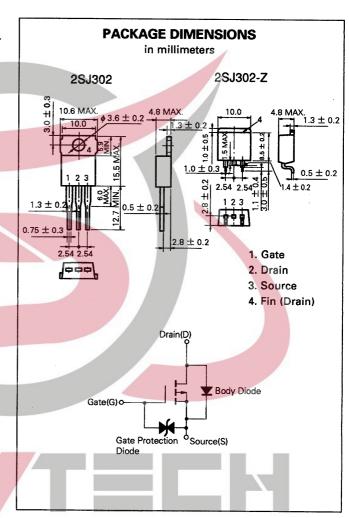
Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

# ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

Drain to Source Voltage	Voss	-60	V
Gate to Source Voltage	Vgss	-20, +10	٧
Drain Current (DC)	ID(DC)	∓16	Α
Drain Current (pulse)	D(pulse)*	<b>∓64</b>	Α
Total Power Dissipation (Tc = 25 °C)	Рт	75	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg -	-55 to +150	°C

\* PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1 %



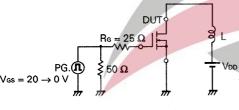
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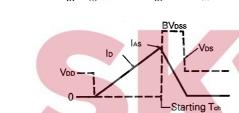
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# ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

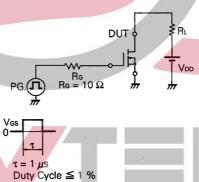
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-state Resistance	RDS(on)		75	100	mΩ	Vgs = -10 V, lp = -8 A
Drain to Source On-state Resistance	RDS(on)		130	240	mΩ	Vgs = -4.0 V, lp = -6 A
Gate to Source Cutoff Voltage	VGS(off)	-1.0		-2.0	V	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -1 mA
Forward Transfer Admittance	lyfsl	5.0			s	V <sub>D</sub> s = -10 V, I <sub>D</sub> = -8 A
Drain Leakage Current	loss			-10	μΑ	V <sub>D</sub> s = -60 V, V <sub>G</sub> s = 0
Gate to Source Leakage Current	lgss			∓10	μΑ	Vgs = ∓16 V, Vps = 0
Input Capacitance	Ciss		1200		pF	V <sub>DS</sub> = -10 V V <sub>GS</sub> = 0 f = 1 MHz
Output Capacitance	Coss		670		pF	
Reverse Transfer Capacitance	Cras		290		pF	
Turn-On Delay Time	td(on)		30		ns	$V_{GS(on)} = -10 \text{ V}$ $V_{DD} = -30 \text{ V}$ $I_{D} = -8 \text{ A, Rg} = 10 \Omega$ $R_{L} = 3.75 \Omega$
Rise Time	tr		170		ns	
Turn-Off Delay Time	td(off)		150		ns	
Fall Time	tr		130		ns	
Total Gate Charge	QG		42		nC	V <sub>G</sub> s = -10 V I <sub>D</sub> = -16 A V <sub>DD</sub> = -48 V
Gate to Source Charge	Qgs		3		nC	
Gate to Drain Charge	QGD		17		nC	
Diode Forward Voltage	VsD		1.0	A	V	I <sub>F</sub> = -16 A, V <sub>G</sub> s = 0
Reverse Recovery Time	trr		110		ns	l <sub>F</sub> = -16 A, V <sub>GS</sub> = 0 di/dt = 50 A/μs
Reverse Recovery Charge	Qrr		220		nC	

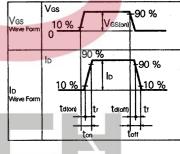
# **Test Circuit 1: Avalanche Capability**





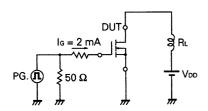
**Test Circuit 2: Switching Time** 



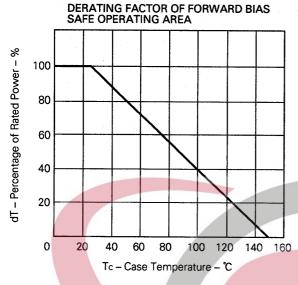


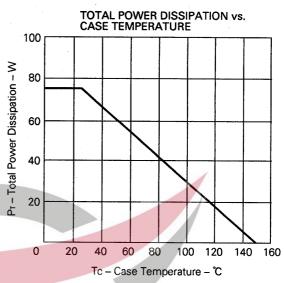
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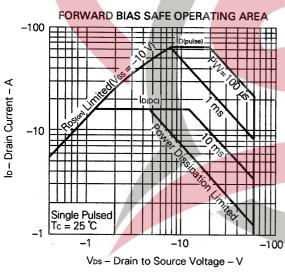
# **Test Circuit 3: Gate Charge**

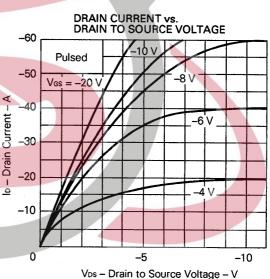


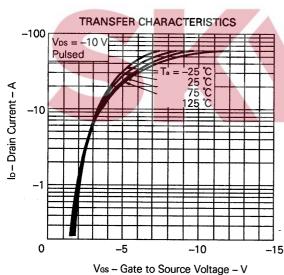
#### TYPICAL CHARACTERISTICS (Ta = 25 °C)



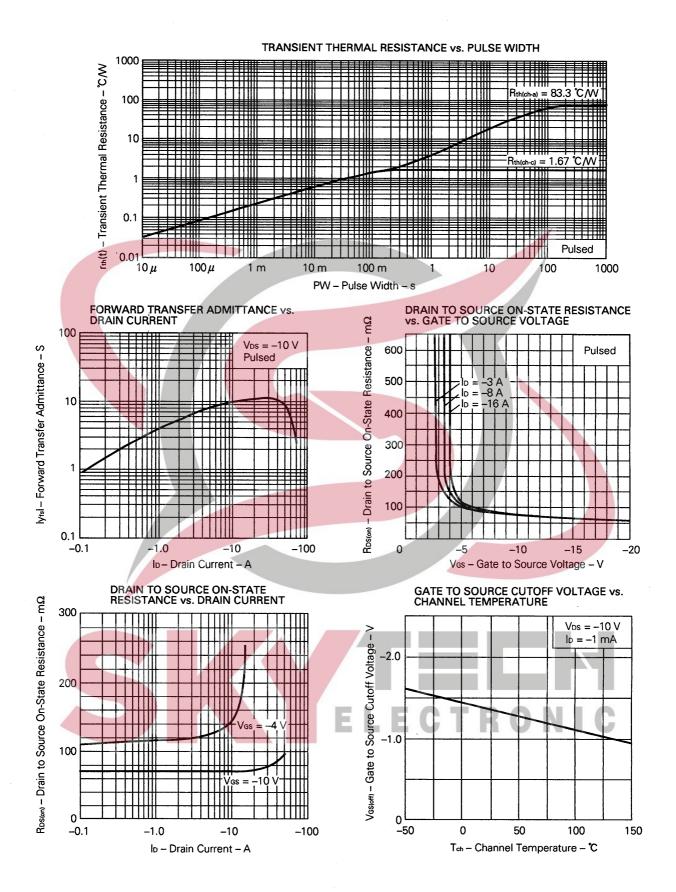


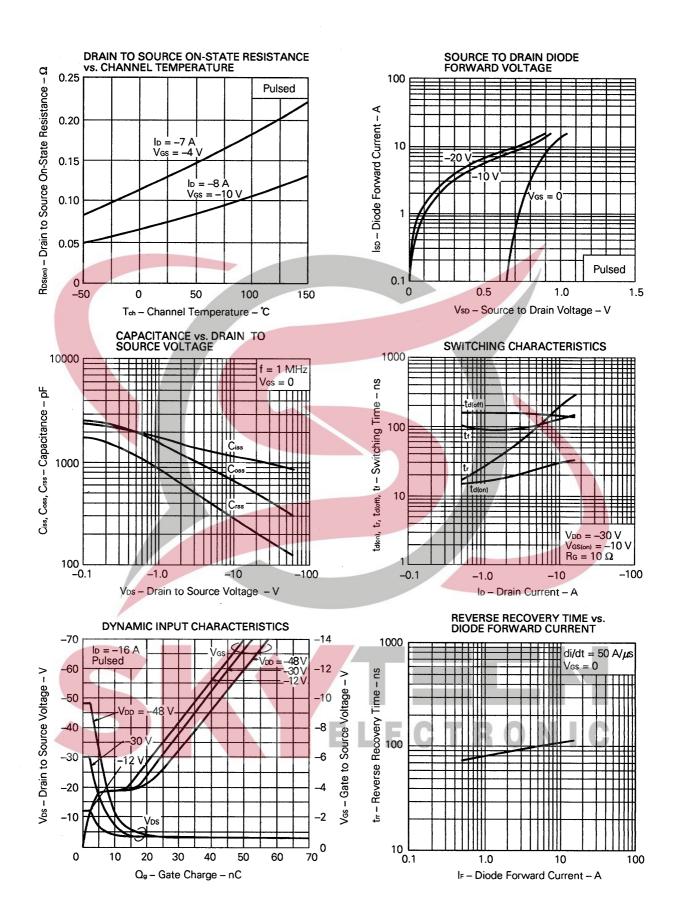


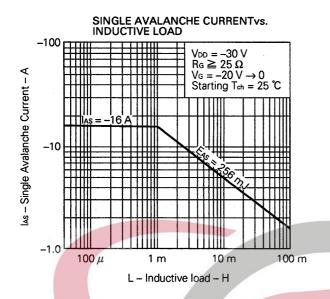


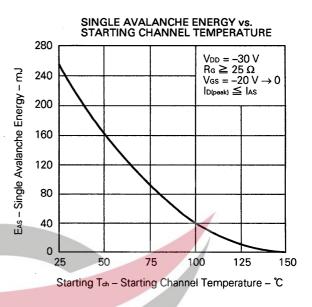


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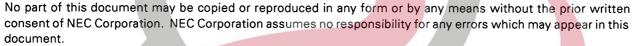
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# Reference

Application note name	No.
Safe operating area of Power MOS FET.	TEA-1034
Application circuit using Power MOS FET.	TEA-1035
Quality control of NEC semiconductors devices.	TEI-1202
Quality control guide of semiconductors devices.	MEI-1202
Assembly manual of semiconductors devices.	IEI-1207



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